

FW005G - FW10G

FAST RECOVERY GLASS PASSIVATED BRIDGE RECTIFIERS

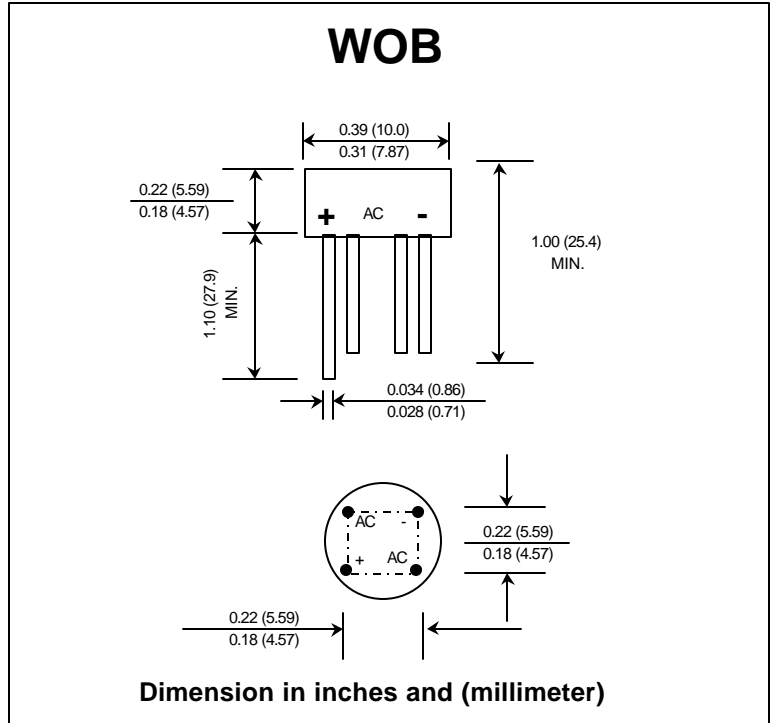
PRV : 50 - 1000 Volts
I_o : 1.5 Amperes

FEATURES :

- * Glass passivated chip
- * High case dielectric strength
- * High surge current capability
- * High reliability
- * Low reverse current
- * Low forward voltage drop
- * Fast switching for high efficiency
- * Ideal for printed circuit board

MECHANICAL DATA :

- * Case : Reliable low cost construction utilizing molded plastic technique
- * Epoxy : UL94V-O rate flame retardant
- * Terminals : Plated leads solderable per MIL-STD-202, Method 208 guaranteed
- * Polarity : Polarity symbols marked on case
- * Mounting position : Any
- * Weight : 1.29 grams



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

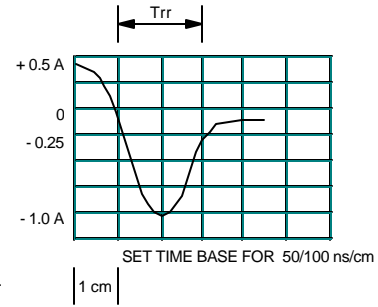
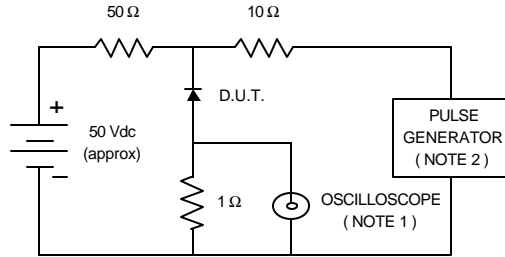
Rating at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

RATING	SYMBOL	FW	FW	FW	FW	FW	FW	FW	UNIT
		005G	01G	02G	04G	06G	08G	10G	
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Current 0.375" (9.5 mm) lead length T _c = 25°C	I _{F(AV)}	1.5							Amps.
Peak Forward Surge Current Single half sine wave Superimposed on rated load (JEDEC Method)	I _{FSM}	30							Amps.
Rating for fusing (t < 8.3 ms.)	I ² t	10							A ² S
Maximum Forward Voltage per Diode at I _F = 1.0 Amp.	V _F	1.3							Volts
Maximum DC Reverse Current T _a = 25 °C at Rated DC Blocking Voltage T _a = 100 °C	I _R	10							µA
	I _{R(H)}	1.0							mA
Maximum Reverse Recovery Time (Note 1)	T _{rr}	150			250	500		ns	
Typical Junction Capacitance per Diode (Note 2)	C _J	24							pf
Typical Thermal Resistance (Note 3)	R _{θJA}	36							°C/W
Operating Junction Temperature Range	T _J	- 50 to + 150							°C
Storage Temperature Range	T _{STG}	- 50 to + 150							°C

Notes : 1) Measured with I_F = 0.5 Amp., I_R = 1 Amp., I_{rr} = 0.25 Amp.
2) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts.
3) Thermal resistance from Junction to Ambient at 0.375" (9.5 mm) lead length P.C. Board mounting.

RATING AND CHARACTERISTIC CURVES (FW005G - FW10G)

FIG.1 - REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



- NOTES : 1. Rise Time = 7 ns max., Input Impedance = 1 megaohm, 22 pF.
 2. Rise time = 10 ns max., Source Impedance = 50 ohms.
 3. All Resistors = Non-inductive Types.

FIG.2 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT

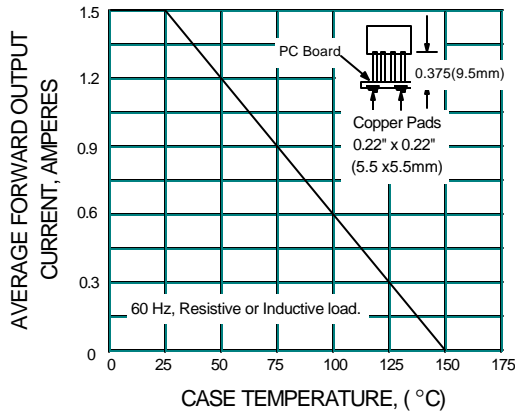


FIG.3 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

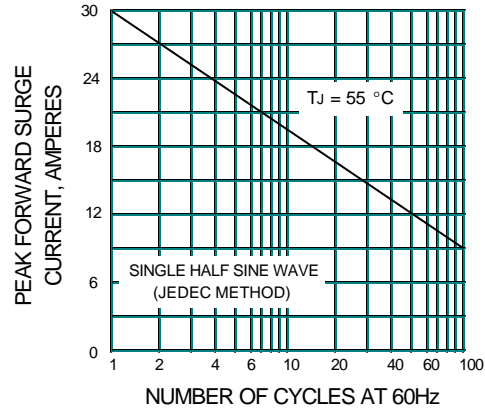


FIG.4 - TYPICAL FORWARD CHARACTERISTICS

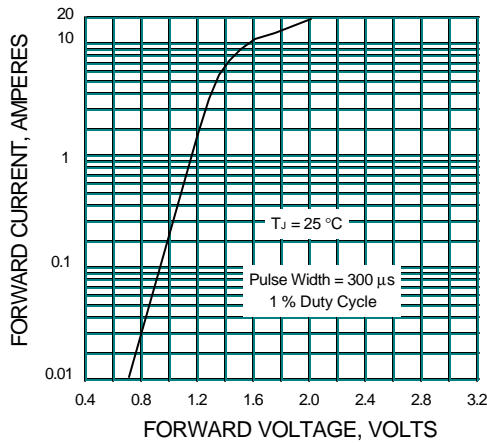


FIG.5 - TYPICAL REVERSE CHARACTERISTICS

